

L Number	Hits	Search Text	DB	Time stamp
-	7417	((438/149) or (438/164) or (438/180) or (438/181) or (438/182) or (438/479) or (438/482) or (438/488) or (438/514) or (438/574) or (438/673) or (438/701) or (438/713) or (438/738) or (438/745) or (438/948)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 14:50
-	430037	tft or (thin near2 film)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 14:49
-	35286	(photoresist near2 pattern) or (photo near2 (mask or masks) )	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/10 21:57
-	9434	(tft or (thin near2 film)) and ((photoresist near2 pattern) or (photo near2 (mask or masks) ))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/09 21:24
-	20524	reticle	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/09 21:24
-	584	((tft or (thin near2 film)) and ((photoresist near2 pattern) or (photo near2 (mask or masks) ))) and reticle	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/09 21:24
-	102	((((438/149) or (438/164) or (438/180) or (438/181) or (438/182) or (438/479) or (438/482) or (438/488) or (438/514) or (438/574) or (438/673) or (438/701) or (438/713) or (438/738) or (438/745) or (438/948)).CCLS.) and reticle	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/09 21:24
-	14668	(ldd or (lightly near2 (doped adj drain)) near2 region)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/09 21:26
-	8	(((((438/149) or (438/164) or (438/180) or (438/181) or (438/182) or (438/479) or (438/482) or (438/488) or (438/514) or (438/574) or (438/673) or (438/701) or (438/713) or (438/738) or (438/745) or (438/948)).CCLS.) and reticle) and ((ldd or (lightly near2 (doped adj drain)) near2 region))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/09 21:27
-	639	((tft or (thin near2 film)) and ((photoresist near2 pattern) or (photo near2 (mask or masks) ))) and ((ldd or (lightly near2 (doped adj drain)) near2 region))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/09 21:27
-	81	((((438/149) or (438/164) or (438/180) or (438/181) or (438/182) or (438/479) or (438/482) or (438/488) or (438/514) or (438/574) or (438/673) or (438/701) or (438/713) or (438/738) or (438/745) or (438/948)).CCLS.) and (((tft or (thin near2 film)) and ((photoresist near2 pattern) or (photo near2 (mask or masks) ))) and ((ldd or (lightly near2 (doped adj drain)) near2 region)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/09 21:27
-	0	6548331.URPN.	USPAT	2004/01/09 21:37
-	11	("5403772"   "5488000"   "5569610"   "5581092"   "5821562"   "6066547"   "6097037"   "6133073"   "6221702"   "6278130"   "6300659").PN.	USPAT	2004/01/09 21:37
-	0	6440784.URPN.	USPAT	2004/01/09 21:38

-	14	("4514253"   "4654117"   "5627103"   "5686326"   "5714790"   "5733804"   "5909615"   "5917199"   "5940151"   "6166785"   "6204520"   "6232158"   "6275275"   "6337234") .PN.	USPAT	2004/01/09 21:38
-	14	("4514253"   "4654117"   "5627103"   "5686326"   "5714790"   "5733804"   "5909615"   "5917199"   "5940151"   "6166785"   "6204520"   "6232158"   "6275275"   "6337234") .PN.	USPAT	2004/01/09 21:40
-	7	5668019.URPN.	USPAT	2004/01/09 21:41
-	7	("4479831"   "4577391"   "4629859"   "4727044"   "4751169"   "4980018"   "5214295") .PN.	USPAT	2004/01/09 21:43
-	5054	t near2 gate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/09 21:44
-	634	(t near2 gate) and (tft or (thin near2 film))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/09 21:45
-	87	((t near2 gate) and (tft or (thin near2 film))) and ((ldd or (lightly near2 (doped adj drain)) near2 region))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/09 21:47
-	0	(wider near (gate same (gate near2 dielectric))) and ((photoresist near2 pattern) or (photo near2 (mask or masks) ))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/09 21:48
-	2	wider near (gate same (gate near2 dielectric))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/09 21:49
-	0	((photoresist near2 pattern) or (photo near2 (mask or masks) )) near (gate same (gate near2 dielectric))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/09 21:49
-	15514	(gate same (gate near2 dielectric))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/09 21:50
-	168	{ (gate same (gate near2 dielectric))) same ((photoresist near2 pattern) or (photo near2 (mask or masks) ))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/09 21:50
-	48	(( (gate same (gate near2 dielectric))) same ((photoresist near2 pattern) or (photo near2 (mask or masks) ))) and (tft or (thin near2 film))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/09 21:52
-	314	tapered near gate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/09 21:53
-	66	(tapered near gate) and (tft or (thin near2 film))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/09 21:53

-	35286	(photoresist near2 pattern) or (photo near2 (mask or masks) )	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/10 21:59
-	837644	gate or (gate near2 electrode)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 15:25
-	326	((photoresist near2 pattern) or (photo near2 (mask or masks) )) near (gate or (gate near2 electrode))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/10 21:59
-	430037	tft or (thin near2 film)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/10 21:59
-	7417	((438/149) or (438/164) or (438/180) or (438/181) or (438/182) or (438/479) or (438/482) or (438/488) or (438/514) or (438/574) or (438/673) or (438/701) or (438/713) or (438/738) or (438/745) or (438/948)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/10 22:00
-	14	(((((photoresist near2 pattern) or (photo near2 (mask or masks) )) near (gate or (gate near2 electrode))) and (tft or (thin near2 film))) and (((438/149) or (438/164) or (438/180) or (438/181) or (438/182) or (438/479) or (438/482) or (438/488) or (438/514) or (438/574) or (438/673) or (438/701) or (438/713) or (438/738) or (438/745) or (438/948)).CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/10 22:00
-	110	((photoresist near2 pattern) or (photo near2 (mask or masks) )) near (gate or (gate near2 electrode))) and (tft or (thin near2 film))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/10 22:02
-	0	6429485.URPN.	USPAT	2004/01/10 22:16
-	0	("3890632"   "5292675"   "5323042"   "5757048"   "6031249").PN.	USPAT	2004/01/10 22:17
-	430033	tft or (thin near2 film)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 15:22
-	63417	color near2 filter	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 15:23
-	7417	((438/149) or (438/164) or (438/180) or (438/181) or (438/182) or (438/479) or (438/482) or (438/488) or (438/514) or (438/574) or (438/673) or (438/701) or (438/713) or (438/738) or (438/745) or (438/948)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 14:51
-	12891	(tft or (thin near2 film)) and (color near2 filter)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 14:51
-	6941	(tft or (thin near2 film)) same (color near2 filter)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 14:51

-	89	((tft or (thin near2 film)) same (color near2 filter)) and (((438/149) or (438/164) or (438/180) or (438/181) or (438/182) or (438/479) or (438/482) or (438/488) or (438/514) or (438/574) or (438/673) or (438/701) or (438/713) or (438/738) or (438/745) or (438/948)).CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 15:01
-	1176	pigment near substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 15:02
-	25	(tft or (thin near2 film)) same (pigment near substrate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 15:02
-	58114	tft or (thin near2 film near2 transistor)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 15:22
-	1200433	(filter (color near2 filter))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 15:23
-	11039	(tft or (thin near2 film near2 transistor)) and ((filter (color near2 filter)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 15:24
-	1671185	pattern\$4 etch\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 15:24
-	7574	((tft or (thin near2 film near2 transistor)) and ((filter (color near2 filter)))) and (pattern\$4 etch\$)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 15:24
-	837638	gate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 15:25
-	4855	((((tft or (thin near2 film near2 transistor)) and ((filter (color near2 filter)))) and (pattern\$4 etch\$)) and gate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 15:26
-	556043	capacitor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 15:26
-	2366	(((((tft or (thin near2 film near2 transistor)) and ((filter (color near2 filter)))) and (pattern\$4 etch\$)) and gate ) and capacitor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 15:27
-	443038	implant\$3 dop\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 15:27
-	1550	(((((tft or (thin near2 film near2 transistor)) and ((filter (color near2 filter)))) and (pattern\$4 etch\$)) and gate ) and capacitor) and (implant\$3 dop\$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 15:31

-	88984	polysilicon	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 15:32
-	720	((((tft or (thin near2 film near2 transistor)) and ((filter (color near2 filter)))) and (pattern\$4 etch\$)) and gate ) and capacitor) and (implant\$3 dop\$4)) and polysilicon	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/11 15:32